- Three Differential Transceivers in One Package
- Signaling Rates† Up to 30 Mbps
- Low Power and High Speed
- Designed for TIA/EIA-485, TIA/EIA-422, ISO 8482, and ANSI X3.277 (HVD SCSI Fast-20) Applications
- Common-Mode Bus Voltage Range
 7 V to 12 V
- ESD Protection on Bus Terminals Exceeds 12 kV
- Driver Output Current up to ±60 mA
- Thermal Shutdown Protection
- Driver Positive and Negative Current Limiting
- Power-Up, Power-Down Glitch-Free Operation
- Pin-Compatible With the SN75ALS170
- Available in Shrink Small-Outline Package

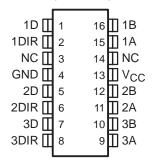
description

The SN65LBC170 and SN75LBC170 are monolithic integrated circuits designed for bidirectional data communication on multipoint bus-transmission lines. Potential applications include serial or parallel data transmission, cabled peripheral buses with twin axial, ribbon, or twisted-pair cabling. These devices are suitable for FAST-20 SCSI and can transmit or receive data pulses as short as 25 ns, with skew less than 3 ns.

These devices combine three 3-state differential line drivers and three differential input line receivers, all of which operate from a single 5-V power supply.

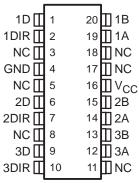
The driver differential outputs and the receiver differential inputs are connected internally to form three differential input/output (I/O) bus ports that are designed to offer minimum loading to the bus whenever the driver is disabled or $V_{CC} = 0$. These ports feature a wide common-mode voltage range making the device suitable for party-line applications over long cable runs.

SN65LBC170DB (marked as BL170) SN75LBC170DB (marked as BL170) (TOP VIEW)



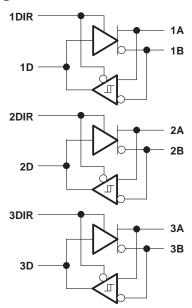
SN65LBC170DW (marked as 65LBC170) SN75LBC170DW (marked as 75LBC170)

(TOP VIEW)



NC - No internal connection

logic diagram





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

†The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).



description (continued)

The driver's active-high enable and the receiver's active-low enable are tied together internally and provide a direction input for each driver/receiver pair.

The SN75LBC170 is characterized for operation over the temperature range of 0°C to 70°C. The SN65LBC170 is characterized for operation over the temperature range of -40°C to 85°C.

AVAILABLE OPTIONS†

	PACKAGE	
TA	PLASTIC SHRINK SMALL-OUTLINE (JEDEC MO-150)	PLASTIC SMALL-OUTLINE (JEDEC MS-013)
0°C to 70°C	SN75LBC170DB	SN75LBC170DW
-40°C to 85°C	SN65LBC170DB	SN65LBC170DW

TAdd R suffix for taped and reel

Function Tables

INPUT	ENABLE	OUT	PUTS
D	DIR	Α	В
Н	Н	Н	L
L	Н	L	Н
OPEN	Н	L	Н
Х	L	Z	Z
X	OPEN	Ιx	Х

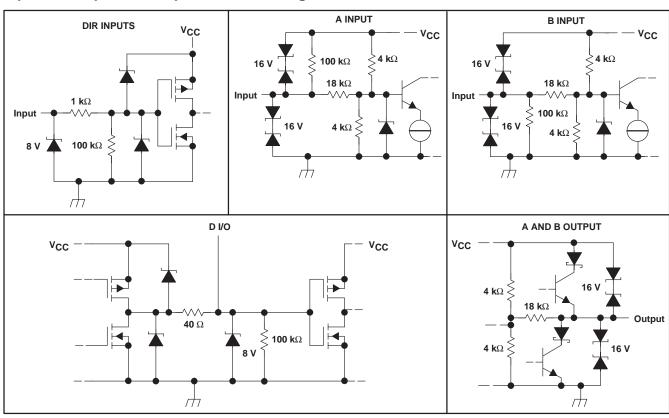
EACH DRIVER

DIFFERENTIAL INPUT (VA-VB)	ENABLE DIR	OUTPUT D
$V_{ID} \ge 0.2 V$	L	Н
$-0.2 \text{ V} < \text{V}_{1D} < 0.2 \text{ V}$	L	?
$V_{ID} \le -0.2 V$	L	L
X	Н	Z
OPEN	L	н

EACH RECEIVER

H = high level, L = low level, X = irrelevant, Z = high impedance (off), ? = indeterminate

equivalent input and output schematic diagrams





[†] For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

absolute maximum ratings[†] over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC} (see Note 1)	0.3 V to 6 V
Voltage range at any bus I/O terminal (steady state)	
Voltage input range, A and B, (transient pulse through 100 Ω , see Figure	re 12)30 V to 30 V
Voltage range at any D or DIR terminal	– 0.5 V to V _{CC} + 0.5 V
Receiver output current, I _O	±10 mA
Electrostatic discharge: Human body model (A, B, GND) (see Note 2)	12 kV
All pins	5 kV
Charged-device model (all pins) (see Note 3)	
Continuous total power dissipation	. See Power Dissipation Rating Table

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.

- 2. Tested in accordance with JEDEC Standard 22, Test Method A114-A.
- 3. Tested in accordance with JEDEC Standard 22, Test Method C101.

POWER DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \leq 25^{\circ}\mbox{\scriptsize C} \\ \mbox{\scriptsize POWER RATING} \\$	DERATING FACTOR [‡] ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	
DB	995 mW	8.0 mW/°C	635 mW	515 mW	
DW	1480 mW	11.8 mW/°C	950 mW	770 mW	

[‡]This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		4.75	5	5.25	V
Voltage at any bus I/O terminal	А, В	-7		12	V
High-level input voltage, VIH	D. DID	2		VCC	
Low-level input voltage, V _{IL}	D, DIR	0		0.8	V
Differential input voltage, V _{ID}	A with respect to B	-12		12	V
Outract	Driver	-60		60	^
Output current	Receiver	-8		8	mA
Or and in the contract of T	SN75LBC170	0		70	20
Operating free-air temperature, T _A	SN65LBC170	-40		85	°C

DRIVER SECTION

electrical characteristics over recommended operating conditions

PARAMETER			TEST CO	ONDITIONS	MIN	TYP [†]	MAX	UNIT
VIK	Input clamp voltage	D and DIR	I _I = 18 mA		-1.5	-0.7		V
VO	Open-circuit output voltage (sin	ngle-ended)	A or B, No load		0		VCC	V
		No load		3.8	4.3	VCC		
Vod(SS)	Steady-state differential output magnitude‡	voltage	$R_L = 54 \Omega$,	See Figure 1	1	1.6	2.4	V
. ,	magnitude		With common-mode	loading, See Figure 2	1	1.6	2.4	
$\Delta V_{ extsf{OD}}$	Change in differential output voltage magnitude, V _{OD(H)} - V _{OD(L)}				-0.2		0.2	V
V _{OC} (SS)	(SS) Steady-state common-mode output voltage		$R_L = 54 \Omega$, $C_L = 50 pF$	See Figure 1	2	2.4	2.8	
Change in steady-state common-mode output voltage ($VOC(H) - VOC(L)$)		οι = 50 μ		-0.2		0.2	V	
I _I Input current		D, DIR		-100		100	μΑ	
IO	Output current with power off		$V_{CC} = 0 V$,	$V_0 = -7 \text{ V to } 12 \text{ V}$	-700		900	μΑ
los	Short-circuit output current		$V_0 = -7 \text{ V to } 12 \text{ V},$	See Figure 7	-250		250	mA
Icc	Supply current (driver enable	d)	D at 0 V or V _{CC} ,	DIR at V _{CC} , No load		14	20	mA

[†] All typical values are at $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

switching characteristics over recommended operating conditions

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
^t PLH	Differential output propagation delay, low-to high		4	8.5	12	
^t PHL	Differential output propagation delay, high-to-low		4	8.5	11	
t _r	Differential output rise time	7	3	7.5	11	
tf	Differential output fall time	$R_L = 54 \Omega$, $C_L = 50 pF$, See Figure 3	3	7.5	11	ns
tsk(p)	Pulse skew (tpLH – tpHL)	7			2	
tsk(o)	Output skew§	7			1.5	
tsk(pp)	Part-to-part skew¶	7			2	
^t PLH	Differential output propagation delay, low-to high		3	7	10	
^t PHL	Differential output propagation delay, high-to-low	7	3	7.5	10	
t _r	Differential output rise time]	3	7.5	12	
tf	Differential output fall time	See Figure 4, (HVD SCSI double-terminated load)	3	7.5	12	ns
t _{sk(p)}	Pulse skew (tpLH – tpHL)	(TVD 3031 double-terminated load)			3	
t _{sk(o)}	Output skew§	7			1.5	
tsk(pp)	Part-to-part skew¶	7			2.5	
^t PZH	Output enable time to high level	Con Figure 5		15	25	
^t PHZ	Output disable time from high level	See Figure 5		18	25	ns
t _{PZL}	Output enable time to low level			10	25	
^t PLZ	Output disable time from low level	See Figure 6		17	25	ns

[§] Output skew (t_{Sk(0)}) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together. Part-to-part skew (t_{sk(pp)}) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.



[‡] The minimum VOD may not fully comply with TIA/EIA-485-A at operating temperatures below 0°C. System designers should take the possibly lower output signal into account in determining the maximum signal-transmission distance.

RECEIVER SECTION

electrical characteristics over recommended operating conditions

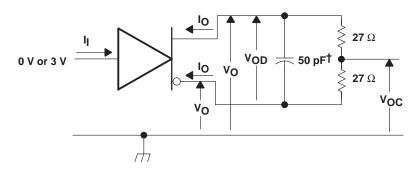
	PARAMETER	TEST CO	MIN	TYP†	MAX	UNIT	
V _{IT+}	Positive-going differential input voltage threshold					0.2	.,
V _{IT} -	Negative-going differential input voltage threshold	See Figure 8		-0.2			V
V _{hys} Hysteresis voltage (V _{IT+} – V _{IT-})			-		40		mV
Vон	High-level output voltage	$V_{ID} = 200 \text{ mV}, I_{OH} = -8 \text{ mA}, \text{ See Figure 8}$		4	4.7	VCC	٧
VOL	Low-level output voltage	$V_{ID} = -200$ mV, $I_{OL} = -8$ mA, See Figure 8		0	0.2	0.4	V
	Line input compat	Oth an import ON	V _I = 12 V			0.9	A
"	Line input current	Other input = 0 V	V _I = −7 V	-0.7			mA
R _I	Input resistance	A, B		12		·	kΩ
ICC	Supply current (receiver enabled)	A, B, D, and DIR open				16	mA

[†] All typical values are at $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

switching characteristics over recommended operating conditions

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
^t PLH	Propagation delay time, low-to-high level output		7		16	ns
tpHL Propagation delay time, high-to-low level output		05	7		16	ns
t _r	Receiver output rise time	See Figure 9		1.3	3	ns
t _f Receiver output fall time				1.3	3	ns
tPZH Receiver output enable time to high level		O		26	40	
^t PHZ	Receiver output disable time from high level	See Figure 10			40	ns
tpzL Receiver output enable time to low level		O		29	40	
tpLZ Receiver output enable time to high level		See Figure 11			40	ns
tsk(p)	Pulse skew (tpLH - tpHL)				2	ns
tsk(o)	Output skew [‡]				1.5	ns
tsk(pp)	Part-to-part skew§				3	ns

[‡] Output skew (t_{sk(o)}) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together. § Part-to-part skew (t_{sk(pp)}) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.



† Includes probe and jig capacitance

Figure 1. Driver Test Circuit, V_{OD} and V_{OC} Without Common-Mode Loading

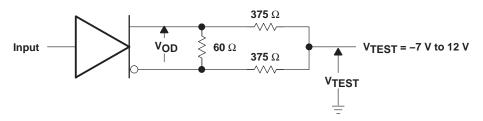


Figure 2. Driver Test Circuit, V_{OD} With Common-Mode Loading

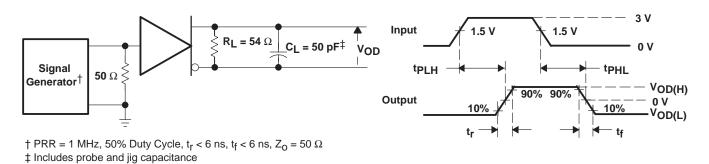
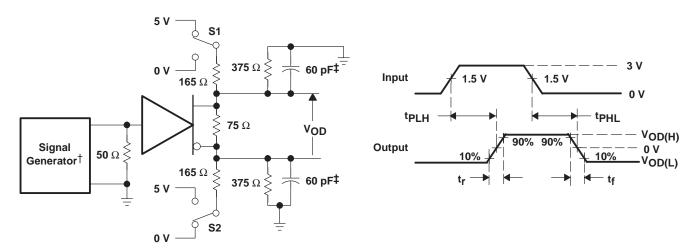
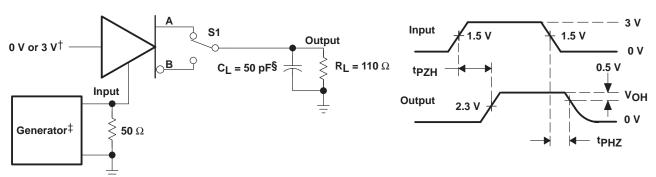


Figure 3. Driver Switching Test Circuit and Waveforms, 485-Loading



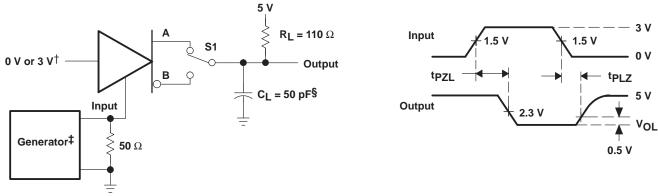
- † PRR = 1 MHz, 50% Duty Cycle, t_{f} < 6 ns, t_{f} < 6 ns, Z_{O} = 50 Ω
- ‡ Includes probe and jig capacitance

Figure 4. Driver Switching Test Circuit and Waveforms, HVD SCSI-Loading (double terminated)



- † 3 V if testing A output, 0 V if testing B output
- \ddagger PRR = 1 MHz, 50% Duty Cycle, t_r < 6 ns, t_f < 6 ns, Z_O = 50 Ω
- § Includes probe and jig capacitance

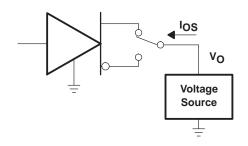
Figure 5. Driver Enable/Disable Test, High Output



- † 0 V if testing A output, 3 V if testing B output
- \ddagger PRR = 1 MHz, 50% Duty Cycle, t_{f} < 6 ns, t_{f} < 6 ns, Z_{O} = 50 Ω
- § Includes probe and jig capacitance

Figure 6. Driver Enable/Disable Test, Low Output





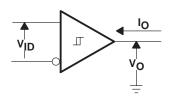
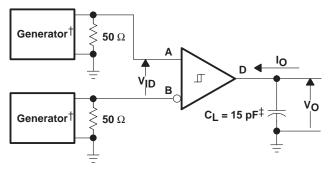


Figure 7. Driver Short-Circuit Test

Figure 8. Receiver DC Parameters







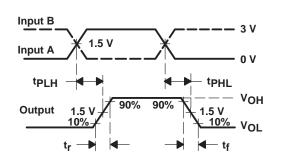
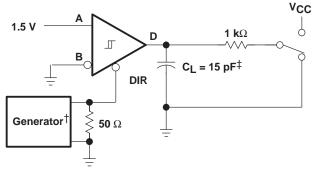
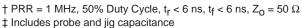


Figure 9. Receiver Switching Test Circuit and Waveforms





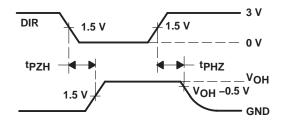
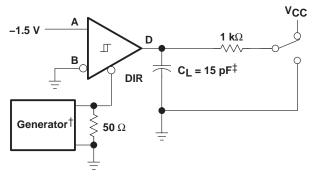
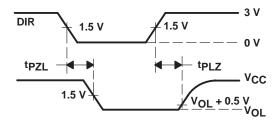


Figure 10. Receiver Enable/Disable Test, High Output





- † PRR = 1 MHz, 50% Duty Cycle, $t_{\rm f}$ < 6 ns, $t_{\rm f}$ < 6 ns, $Z_{\rm O}$ = 50 Ω
- ‡ Includes probe and jig capacitance

Figure 11. Receiver Enable/Disable Test, Low Output

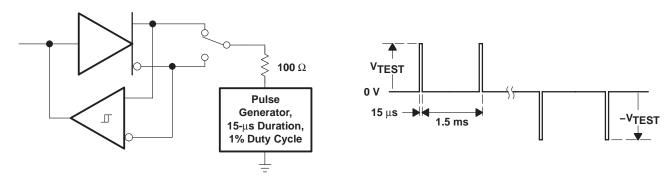
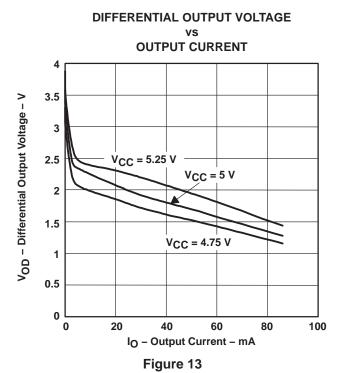
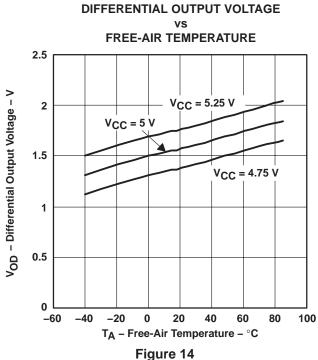
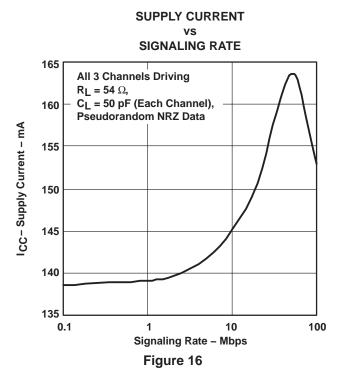


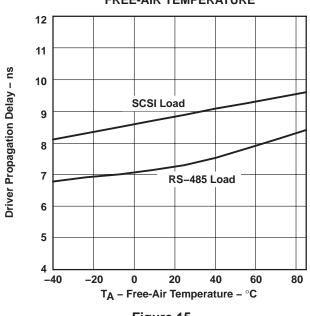
Figure 12. Test Circuit and Waveform, Transient Over Voltage Test





DRIVER PROPAGATION DELAY FREE-AIR TEMPERATURE 12 11





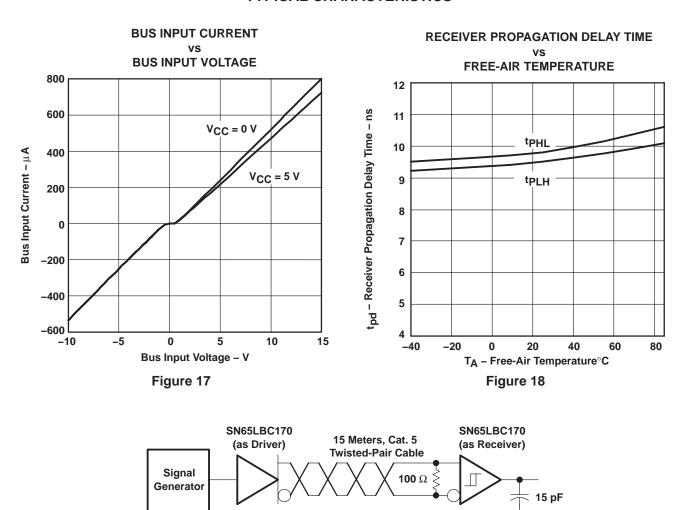


Figure 19. Circuit Diagram for Signaling Characteristics

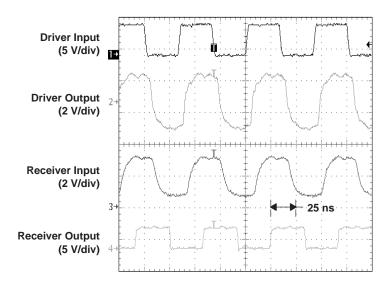


Figure 20. Signal Waveforms at 30 Mbps

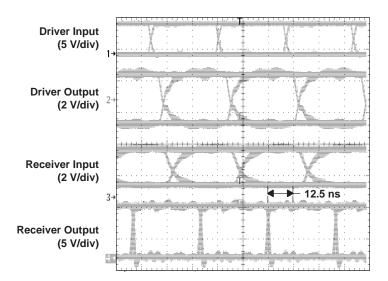


Figure 21. Eye Patterns, Pseudorandom Data at 30 Mbps

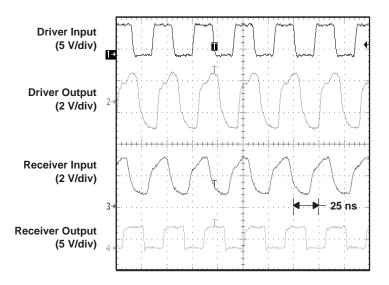


Figure 22. Signal Waveforms at 50 Mbps

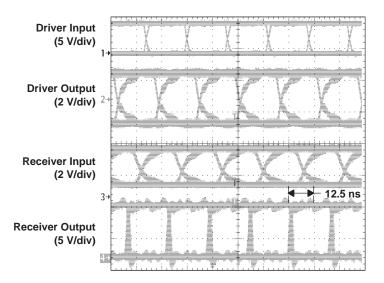


Figure 23. Eye Patterns, Pseudorandom Data at 50 Mbps

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN65LBC170DB	ACTIVE	SSOP	DB	16	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	BL170	Samples
SN65LBC170DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC170	Samples
SN75LBC170DB	ACTIVE	SSOP	DB	16	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LB170	Samples
SN75LBC170DBR	ACTIVE	SSOP	DB	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	LB170	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75LBC170DBR	SSOP	DB	16	2000	330.0	16.4	8.35	6.6	2.5	12.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

	Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
ı	SN75LBC170DBR	SSOP	DB	16	2000	356.0	356.0	35.0	

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN65LBC170DB	DB	SSOP	16	80	530	10.5	4000	4.1
SN65LBC170DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN75LBC170DB	DB	SSOP	16	80	530	10.5	4000	4.1



SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.





SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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